	1 A A A A A A A A A A A A A A A A A A A
ΡΛΝ	JIT
	SEMI
	CONDUCTOR

40V P-Channel Enhancement Mode MOSFET

Voltage

Current -100 A

Features

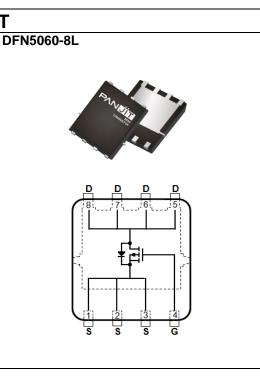
- Rds(on), Vgs@-10V, Id@-20A<6mΩ
- $R_{DS(ON)}$, V_{GS} @-4.5V, I_D @-10A<9.1m Ω

-40 V

- 100% UIS tested
- Reliable and Rugged
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : DFN5060-8L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.08 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETE	R	SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V _{DS}	-40	
Gate-Source Voltage		V _{GS}	±25	V
Continuous Drain Current ^(Note 3)	T _C =25°C		-100	
	Tc=100°C	I _D	-70	А
Pulsed Drain Current ^(Note 1)	T _c =25°C	I _{DM}	-336	
Power Dissipation	T _c =25°C	D -	107	14/
	Tc=100°C	PD	54	W
Continuous Drain Current ^(Note 4)	T _A =25°C		-17.6	
	T _A =70°C	I _D	-14.7	— A
Power Dissipation	T _A =25 [°] C	Da	3.3	10/
	T _A =70°C	PD	2.3	W
Single Pulse Avalanche Energy ^{(Note}	e 5)	Eas	182	mJ
Operating Junction and Storage Temperature Range		TJ,TSTG	-55~175	°C
Thermal Resistance ^(Note 4)	Junction to Case	R _{θJC}	1.4	°C/W
	Junction to Ambient	R _{θJA}	45	C/W



Electrical Characteristics (T_A=25°C unless otherwise noted)

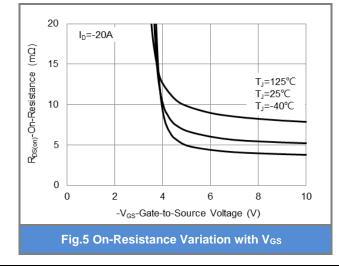
PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250uA	-40	-	-	V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250uA	-1	-2	-2.5	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-20A	-	4.8 6		mΩ
		V _{GS} =-4.5V, I _D =-10A -		7	9.1	
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =-40V, V_{GS} =0V	-	-	-1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±25V, V _{DS} =0V	-	-	±100	nA
Dynamic ^(Note 6)	-		-	•		
Total Gate Charge	Qg		-	100	-	
Gate-Source Charge	Qgs	V _{DS} =-32V, I _D =-20A, V _{GS} =-10V	-	17	-	nC
Gate-Drain Charge	Q_{gd}	VGS=-10V	-	23	-	
Input Capacitance	Ciss		-	5790	-	pF
Output Capacitance	Coss	V _{DS} =-25V, V _{GS} =0V, f=1MHz	-	463	-	
Reverse Transfer Capacitance	Crss		-	291	-	
Gate resistance	Rg	f=1MHz	-	11	-	Ω
Turn-On Delay Time	td(on)		-	10	-	
Turn-On Rise Time	tr	V _{DS} =-32, I _D =-20A,	-	9	-	
Turn-Off Delay Time	td _(off)	V _{GS} =-10V, R _G =3Ω	-	211	-	ns
Turn-Off Fall Time	tf		-	150	-	
Drain-Source Diode	-		-	_	-	
Diode Forward Current	Is	T _c =25°C	-	-	-100	_
Pulsed Diode Forward Current	I _{SM}	1C=20 C	-	-	-336	A
Diode Forward Voltage	V _{SD}	Is=-20A, V _{GS} =0V	-	-0.85	-1.3	V
Reverse Recovery Time	Trr	V _{GS} =0V, I _S =-20A	-	19	-	ns
Reverse Recovery Charge	Qrr	dls/dt=100A/us	-	6	-	nC

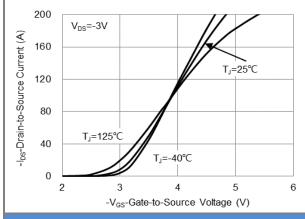
NOTES :

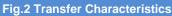
- 1. Pulse width<300us, Duty cycle<2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. The maximum current rating is package limited.
- 4. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 5. The test condition is L=0.5mH, I_{AS}=-27A, V_{DD}=-30V, V_{GS}=-10V, Starting T_J=25°C.
- 6. Guaranteed by design, not subject to production testing.

Fig.3 On-Resistance vs. Drain Current

40







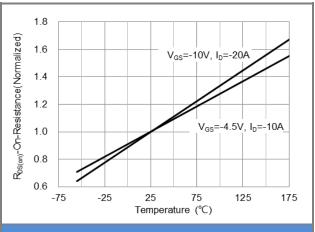
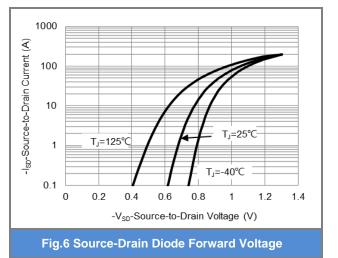


Fig.4 On-Resistance vs. Junction temperature



PJQ5449E-AU

TYPICAL CHARACTERISTIC CURVES

V_{GS}=-10V V_{GS}=-8V

V_{GS}=-6V V_{GS}=-4.5V

4

5

200

160

120

80

40

0

12

10

8

6

4

2

0

20

g

Ros(on)-On-Resistance

0

1

2

Fig.1 On-Region Characteristics

-V_{DS}-Drain-to-Source Voltage (V)

V_{GS}=-4.5V

V_{GS}=-10V

-I_{DS}-Drain-to-Source Current (A)

60

80

100

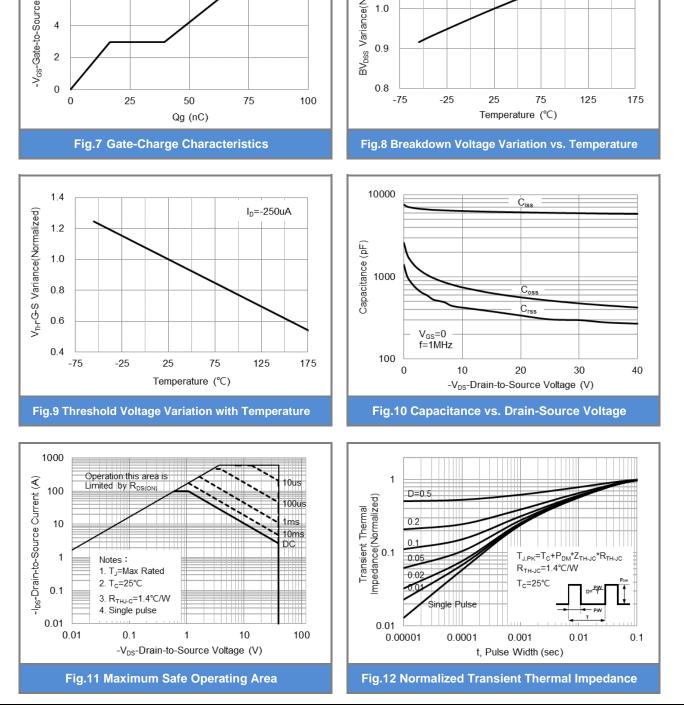
3

-I_{DS}-Drain-to-Source Current (A)

April 18,2023

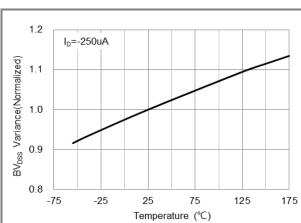
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TYPICAL CHARACTERISTIC CURVES

10 V_{DS}=-32V I_D=-20A -V_{GS}-Gate-to-Source Voltage (V) 8 6



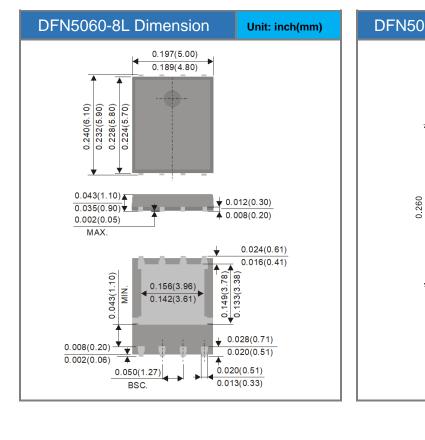
PJQ5449E-AU

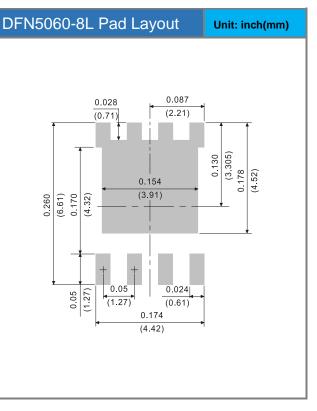


Product and Packing Information

Part No.	Package Type	Packing Type	Marking
PJQ5449E-AU	DFN5060-8L	3K pcs / 13" reel	Q5449E

Packaging Information & Mounting Pad Layout







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